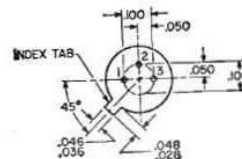
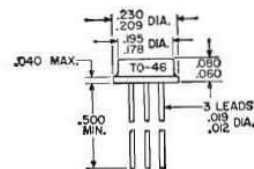
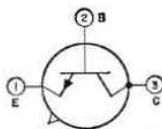


TRANSISTOR

2N2900

Silicon n-p-n type used in a wide variety of small-signal and low-to-medium power applications in military and industrial equipment. It features extremely low leakage characteristics, high pulse beta, high

small-signal beta, very low capacitance, and large gain-bandwidth product. JEDEC No. TO-46 package; outline 18, Outlines Section. This type is electrically identical with type 2N2897.



- 18 -